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Author index

Agosteo, S., T. Nakamura, M. Silari and Z. Zajacova, Attenuation curves in concrete of neutrons from 100 to 400 MeV per nucleon He, C, Ne, Ar, Fe and Xe ions on various targets 217 (2004) 221
Aidinis, C.J., see Mair, G.L.R. 217 (2004) 347
Aït Abderrahim, H., see van der Meer, K. 217 (2004) 202
Akedo, J., see Wang, Q. 217 (2004) 598
Akhmadaliev, Ch., see Mair, G.L.R. 217 (2004) 347
Aktas, O.C., see Biswas, A. 217 (2004) 39
Alcón, E.P.Q., A digital detector performance evaluation using Monte Carlo technique 217 (2004) 361
Alves, E., see Barradas, N.P. 217 (2004) 479
Anagnostakis, E.A., see Mair, G.L.R. 217 (2004) 347
Andersson, P., see Sandström, J. 217 (2004) 513
Ariyasinghe, W.M., T. Wijeratne and P. Palihawadana, Total electron scattering cross sections of CH_4 and NH_3 molecules in the energy range 400–4000 eV 217 (2004) 389
Asano, M., see Takahashi, S. 217 (2004) 435
Aubert, J., see Coste, Ph. 217 (2004) 342
Avasthi, D.K., see Biswas, A. 217 (2004) 39
Avasthi, D.K., see Chaudhuri, S. 217 (2004) 589

Bačáková, L., see Švorčík, V. 217 (2004) 307
Bai, X.D., X.W. Chen, J. Xu, Q.G. Zhou and B.S. Chen, Corrosion resistance and microstructure of zircaloy-4 subjected to ion irradiation 217 (2004) 293
Balaji, S., P.V. Satyam, V. Lakshminarayanan and S. Mohan, Influence of secondary ion bombardment on the composition, structure and surface properties of platinum thin films 217 (2004) 423
Bar, D., see van der Meer, K. 217 (2004) 202
Barashenkov, V.S., H. Kumawat, V.A. Lobanova and V. Kumar, Mathematical model of the electronuclear set-up on the beam of JINR synchrotron 217 (2004) 352
Barklie, R.C., see O'Raifeartaigh, C. 217 (2004) 442
Barradas, N.P., E. Alves, S. Pereira, V.V. Shvartsman, A.L. Kholkin, E. Pereira K.P. O'Donnell, C. Liu, C.J. Deatcher, I.M. Watson and M. Mayer, Roughness in GaN/InGaN films and multilayers determined with Rutherford backscattering 217 (2004) 479
Barros Leite, C.V., see Dias da Cunha, K. 217 (2004) 649
Barry, B. and A. Markwitz, A method for improving the efficiency of proton microprobe profiling of strontium in otoliths using a vacuum compatible NaI detector 217 (2004) 521
Basnar, B., see Lugstein, A. 217 (2004) 402
Bäuerle, D., see Švorčík, V. 217 (2004) 307
Baumann, H., see Markwitz, A. 217 (2004) 583
Bell, J., see Tesfamichael, T. 217 (2004) 97
Berkovits, D., see van der Meer, K. 217 (2004) 202
Bertagnolli, E., see Lugstein, A. 217 (2004) 402
Bhattacharya, D., see Mandal, A.C. 217 (2004) 104
Bhattacharyya, D., see Chaudhuri, S. 217 (2004) 589
Bischoff, L., see Mair, G.L.R. 217 (2004) 347
Bishop, S., see Greife, U. 217 (2004) 1
Biswas, A., D.K. Avasthi, D. Fink, J. Kanzow, U. Schürmann, S.J. Ding, O.C. Aktas, U. Saeed, V. Zaporojtchenko, F. Faupel, R. Gupta and N. Kumar, Nanoparticle architecture in carbonaceous matrix upon swift heavy ion irradiation of polymer–metal nanocomposites 217 (2004) 39

doi:10.1016/S0168-583X(04)00445-8

Biswas, S., see Chaudhuri, S. ... 217 (2004) 589
Blostein, J.J., J. Dawidowski and J.R. Granada, Final energy distributions in deep inelastic neutron scattering experiments ... 217 (2004) 333
Bohne, W., J. Röhrich, A. Schöpke, B. Selle, I. Sieber, W. Fuhs, Á. del Prado, E. San Andrés, I. Mártil and G. González-Díaz, Compositional analysis of thin SiO_xN_y:H films by heavy-ion ERDA, standard RBS, EDX and AES: a comparison ... 217 (2004) 237
Bolbos, R., see Hermanne, A. ... 217 (2004) 193
Boudreault, G., G. Claudio, C. Jeynes, R. Low and B.J. Sealy, Accurate calibration of the retained fluence from a versatile single wafer implanter using RBS ... 217 (2004) 177
Brede, H.J., see Greif, K.-D. ... 217 (2004) 505
Buchmann, L., see Greife, U. ... 217 (2004) 1

Calcagnile, L., see Quarta, G. ... 217 (2004) 644
Ceylan, M., see Zengin, R. ... 217 (2004) 327
Chakraborty, P., see Mohapatra, S. ... 217 (2004) 578
Chatterjee, M.L., see Greife, U. ... 217 (2004) 1
Chaudhuri, S., S. Biswas, A. Gupta, D.K. Avasthi, D. Bhattacharyya, S. Teichert and D.K. Sarkar, Formation of transition metal silicides by high energy ion beam mixing in Mn/Si and Ni/Si single and multilayer samples ... 217 (2004) 589
Chen, A.A., see Greife, U. ... 217 (2004) 1
Chen, B.S., see Bai, X.D. ... 217 (2004) 293
Chen, X.W., see Bai, X.D. ... 217 (2004) 293
Chettle, D.R., see Fleming, D.E.B. ... 217 (2004) 471
Cho, K., see Kim, H. ... 217 (2004) 429
Claudio, G., see Boudreault, G. ... 217 (2004) 177
Codegoni, D., A. Colder, N. Croitoru, P. D'Angelo, M. DeMarchi, G. Fallica, A. Favalli, S. Leonardi, M. Levalois, P. Marie, R. Modica, P.G. Rancoita and A. Seidman, Investigation of irradiated monolithic transistors for space applications ... 217 (2004) 65
Colder, A., see Codegoni, D. ... 217 (2004) 65
Coste, Ph., L. Wartski, J. Aubert and C. Schwebel, A simple microwave component for the vacuum window protection in an ECR ion source for ion beam processing ... 217 (2004) 342
Croitoru, N., see Codegoni, D. ... 217 (2004) 65

D'Angelo, P., see Codegoni, D. ... 217 (2004) 65
Daolio, S., see Tolstogouzov, A. ... 217 (2004) 246
Daudin, L., see Gallien, J.-P. ... 217 (2004) 113
Daum, M., see van der Meer, K. ... 217 (2004) 202
D'Auria, J.M., see Greife, U. ... 217 (2004) 1
Dawidowski, J., see Blostein, J.J. ... 217 (2004) 333
Deatcher, C.J., see Barradas, N.P. ... 217 (2004) 479
de Hosson, J.Th.M., see Escobar Galindo, R. ... 217 (2004) 262
Dekelver, S., see van der Meer, K. ... 217 (2004) 202
D'Elia, M., see Quarta, G. ... 217 (2004) 644
del Prado, Á., see Bohne, W. ... 217 (2004) 237
DeMarchi, M., see Codegoni, D. ... 217 (2004) 65
Dheenathayalu, M., see Ponnusamy, V. ... 217 (2004) 611
Dias da Cunha, K., C.V. Barros Leite and Z. Zays, Exposure to mineral sands dust particles ... 217 (2004) 649
DiMichiel, M., see Nazmov, V. ... 217 (2004) 409
Ding, F.-R., P. Shi, W.-H. He, Y. Wang, R. Nie, D.-Y. Shen and H.-J. Ma, Secondary ion emissions from carbon nanotubes induced by MeV Si and Si_2 clusters ... 217 (2004) 572
Ding, S.J., see Biswas, A. ... 217 (2004) 39
Ditrói, F., see Tárkányi, F. ... 217 (2004) 373
Ditrói, F., see Tárkányi, F. ... 217 (2004) 531
Dityuk, A.I., see Tárkányi, F. ... 217 (2004) 373
Doyle, J.M., see Dzhosyuk, S.N. ... 217 (2004) 457
Dvořánková, B., see Švorčík, V. ... 217 (2004) 307

Dzhosyuk, S.N., C.E.H. Mattoni, D.N. McKinsey, A.K. Thompson, L. Yang, J.M. Doyle and P.R. Huffman, Neutron-induced luminescence and activation in neutron shielding and scintillation detection materials at cryogenic temperatures 217 (2004) 457

Endo, I., D. Iseki, T. Ohnishi, C. Moriyoshi and A.V. Shchagin, On the origin of mysterious X-ray spectral peaks observed at the REFER electron ring 217 (2004) 666
Ene, A., see Lupu, R. 217 (2004) 123
Engel, S., see Greife, U. 217 (2004) 1
Escobar Galindo, R., A. van Veen, J.H. Evans, H. Schut and J.Th.M. de Hosson, Protrusion formation and surface porosity development on thermally annealed helium implanted copper 217 (2004) 262
Escobar Galindo, R., see Evans, J.H. 217 (2004) 276
Evans, J.H., see Escobar Galindo, R. 217 (2004) 262
Evans, J.H., R. Escobar Galindo and A. van Veen, A description of bubble growth and gas release during thermal annealing of helium implanted copper 217 (2004) 276

Fallica, G., see Codegoni, D. 217 (2004) 65
Faupel, F., see Biswas, A. 217 (2004) 39
Favalli, A., see Codegoni, D. 217 (2004) 65
Feng, J.Y., see Xu, J.L. 217 (2004) 33
Fernández, P.L., L.S. Quindós, C. Sainz and J. Gómez, A theoretical approach to the measurement of radon diffusion and adsorption coefficients in radonproof membranes 217 (2004) 167
Fernández Timón, A., see Jurado Vargas, M. 217 (2004) 564
Fink, D., see Biswas, A. 217 (2004) 39
Fleming, D.E.B., D.R. Chettle, F.E. McNeill and A.G.P. Weedon, Effects of measurement distance and source activity on the precision of X-ray fluorescence measurements of lead in a bone phantom 217 (2004) 471
Foucher, Y., see van der Meer, K. 217 (2004) 202
Frankenberg, D., see Greif, K.-D. 217 (2004) 505
Friedland, E., Dependence of amorphization energies in SiC on electronic stopping 217 (2004) 396
Fritioff, K., see Sandström, J. 217 (2004) 513
Fromknecht, R., see Yang, B. 217 (2004) 60
Fuhs, W., see Bohne, W. 217 (2004) 237

Gallien, J.-P., B. Orberger, L. Daudin, D.L. Pinti and J. Pasava, Nitrogen in biogenic and abiogenic minerals from Paleozoic black shales: an NRA study 217 (2004) 113
Ganetsos, Th., see Mair, G.L.R. 217 (2004) 347
Garibotti, C.R., see Otranto, S. 217 (2004) 12
Gasaneo, G., see Otranto, S. 217 (2004) 12
Gerber, J., see van der Meer, K. 217 (2004) 202
Giesen, U., see Greif, K.-D. 217 (2004) 505
Gigliotti, D., see Greife, U. 217 (2004) 1
Goldberg, M.B., see van der Meer, K. 217 (2004) 202
Gómez, J., see Fernández, P.L. 217 (2004) 167
González-Díaz, G., see Bohne, W. 217 (2004) 237
Gordon, J., Simplified modelling of an ion linac used for ion implantation 217 (2004) 143
Granada, J.R., see Blostein, J.J. 217 (2004) 333
Greif, K.-D., H.J. Brede, D. Frankenberg and U. Giesen, The PTB single ion microbeam for irradiation of living cells 217 (2004) 505
Greife, U., S. Bishop, L. Buchmann, M.L. Chatterjee, A.A. Chen, J.M. D'Auria, S. Engel, D. Gigliotti, D. Hunter, D.A. Hutcheon, A. Hussein, C.C. Jewett, A.M. Laird, M. Lamey, W. Liu, A. Olin, D. Ottewell, J. Rogers and C. Wrede, Energy loss around the stopping power maximum of Ne, Mg and Na ions in hydrogen gas 217 (2004) 1
Gu, C., see Sun, Q. 217 (2004) 300
Guedes, S., J.C. Hadler Neto, P. José Iunes and C.A. Tello Saenz, Kinetic model for the relationship between confined fission-track length shortening and fission-track age reduction in minerals 217 (2004) 627

Guo, Z., see Zhao, Z. 217 (2004) 621
Gupta, A., see Chaudhuri, S. 217 (2004) 589
Gupta, R., see Biswas, A. 217 (2004) 39
Gurbich, A.F., On the concept of an actual Coulomb barrier 217 (2004) 183
Güven, O., see Saraydın, D. 217 (2004) 281

Hadler Neto, J.C., see Guedes, S. 217 (2004) 627
Hajdas, W., see van der Meer, K. 217 (2004) 202
Han, H.S., see Kim, H. 217 (2004) 429
Haneda, H., see Sakaguchi, I. 217 (2004) 417
Hanstorp, D., see Sandström, J. 217 (2004) 513
Hassan, G.M., see Sharaf, M.A. 217 (2004) 603
Hayakawa, S., see Ma, C.-J. 217 (2004) 657
He, S., see Hu, Z. 217 (2004) 321
He, W.-H., see Ding, F.-R. 217 (2004) 572
Heitz, J., see Švorčík, V. 217 (2004) 307
Hemalatha, J., see Ponnusamy, V. 217 (2004) 611
Hermanne, A., S. Takács, F. Tárkányi and R. Bolbos, Experimental cross sections for charged particle production of the therapeutic radionuclide ^{111}Ag and its PET imaging analogue ^{104mg}Ag 217 (2004) 193
Hermanne, A., see Tárkányi, F. 217 (2004) 373
Hermanne, A., see Tárkányi, F. 217 (2004) 531
Hirao, K., see Nakamura, N. 217 (2004) 51
Hishita, S., see Sakaguchi, I. 217 (2004) 417
Hnatowicz, V., see Švorčík, V. 217 (2004) 307
Hong, S.K., see Kim, H. 217 (2004) 429
Hu, P., J. Zhang, Q. Jin, L. Shi and Z. Zhou, Proton elastic scattering cross sections of titanium from 1.0 to 3.0 MeV at the laboratory angle of 151° 217 (2004) 551
Hu, Z., S. He and D. Yang, Effect of <200 keV proton radiation on electric properties of silicon solar cells at 77 K 217 (2004) 321
Huber, N., see Švorčík, V. 217 (2004) 307
Huffman, P.R., see Dzhosyuk, S.N. 217 (2004) 457
Hunter, D., see Greife, U. 217 (2004) 1
Hussein, A., see Greife, U. 217 (2004) 1
Hutcheon, D.A., see Greife, U. 217 (2004) 1

Iseki, D., see Endo, I. 217 (2004) 666
Ishikawa, H., see Wang, Q. 217 (2004) 598

Jewett, C.C., see Greife, U. 217 (2004) 1
Jeynes, C., see Boudreault, G. 217 (2004) 177
Jiang, S.H., see Sheu, R.J. 217 (2004) 555
Jin, Q., see Hu, P. 217 (2004) 551
Johnson, S., see Markwitz, A. 217 (2004) 583
José Iunes, P., see Guedes, S. 217 (2004) 627
Joseph, B., see Mohapatra, S. 217 (2004) 578
Jurado Vargas, M. and A. Fernández Timón, Scattering and self-absorption corrections in the measurement of α-particle emitters in 2π geometry 217 (2004) 564

Kanzow, J., see Biswas, A. 217 (2004) 39
Karadag, E., see Saraydın, D. 217 (2004) 281
Kasahara, M., see Ma, C.-J. 217 (2004) 657
Keinonen, J., see Peltola, J. 217 (2004) 25
Kelly, I., see Tesfamichael, T. 217 (2004) 97

Kennedy, V.J., see Markwitz, A. ... 217 (2004) 583
Kholkin, A.L., see Barradas, N.P. ... 217 (2004) 479
Kim, H., K. Park, B. Min, J.S. Lee, K. Cho, S. Kim, H.S. Han, S.K. Hong and T. Yao, Transmuted isotopes doped in neutron-irradiated ZnO thin films ... 217 (2004) 429
Kim, S., see Kim, H. ... 217 (2004) 429
Klockenkämper, R., see von Bohlen, A. ... 217 (2004) 158
Koivisto, H., see Tarvainen, O. ... 217 (2004) 136
Koptagel, E., see Saraydın, D. ... 217 (2004) 281
Koshikawa, H., see Zhu, Z. ... 217 (2004) 449
Kouznetsov, S., see Nazmov, V. ... 217 (2004) 409
Krzyżanowska, H., see von Bohlen, A. ... 217 (2004) 158
Kumar, N., see Biswas, A. ... 217 (2004) 39
Kumar, V., see Barashenkov, V.S. ... 217 (2004) 352
Kumawat, H., see Barashenkov, V.S. ... 217 (2004) 352

Laird, A.M., see Greife, U. ... 217 (2004) 1
Lakshminarayanan, V., see Balaji, S. ... 217 (2004) 423
Lamey, M., see Greife, U. ... 217 (2004) 1
Lee, J.S., see Kim, H. ... 217 (2004) 429
Lehmann, E.H., see van der Meer, K. ... 217 (2004) 202
Leonardi, S., see Codegoni, D. ... 217 (2004) 65
Levalois, M., see Codegoni, D. ... 217 (2004) 65
Linder, H.-P., see van der Meer, K. ... 217 (2004) 202
Lindner, J.K.N., see O'Raifeartaigh, C. ... 217 (2004) 442
Liu, C., see Barradas, N.P. ... 217 (2004) 479
Liu, W., see Greife, U. ... 217 (2004) 1
Lobanova, V.A., see Barashenkov, V.S. ... 217 (2004) 352
Low, R., see Boudreault, G. ... 217 (2004) 177
Lugstein, A., B. Basnar and E. Bertagnolli, Study of the chemical and morphological evolution of the GaAs surface after high fluence focused ion beam exposure ... 217 (2004) 402
Lupu, R., A. Nat and A. Ene, Determination of gold in Romanian auriferous alluvial sands and rocks by 14 MeV neutron activation analysis ... 217 (2004) 123

Ma, C.-J., S. Tohno, M. Kasahara and S. Hayakawa, Determination of the chemical properties of residues retained in individual cloud droplets by XRF microprobe at SPring-8 ... 217 (2004) 657
Ma, H.-J., see Ding, F.-R. ... 217 (2004) 572
Ma, X., see Sun, Q. ... 217 (2004) 300
Maekawa, Y., see Zhu, Z. ... 217 (2004) 449
Mahapatra, D.P., see Mohapatra, S. ... 217 (2004) 578
Mair, G.L.R., Ch. Akhmadaliev, L. Bischoff, Th. Ganetsos, C.J. Aidinis and E.A. Anagnostakis, The effect of electrode geometry on the stability of a liquid metal ion emitter ... 217 (2004) 347
Malambu, E., see van der Meer, K. ... 217 (2004) 202
Manam, J. and S.K. Sharma, Thermally stimulated luminescence studies of undoped and doped $K_2B_4O_7$ compounds ... 217 (2004) 314
Mandal, A.C., S. Santra, D. Mitra, M. Sarkar and D. Bhattacharya, Bremsstrahlung excited standardless EDXRF analysis ... 217 (2004) 104
Mardor, I., see van der Meer, K. ... 217 (2004) 202
Marghitu, O., see Marghitu, S. ... 217 (2004) 498
Marghitu, S., O. Marghitu, C. Oproiu, G. Marin and Fl. Scarlat, Diagnosis and dynamics in a simple low energy medium current electron beam channel ... 217 (2004) 498
Marie, P., see Codegoni, D. ... 217 (2004) 65
Marin, G., see Marghitu, S. ... 217 (2004) 498
Markwitz, A., see Barry, B. ... 217 (2004) 521
Markwitz, A., V.J. Kennedy, S. Johnson, W.J. Trompetter, M. Rudolphi and H. Baumann, SiC nanoboulders on silicon – a nuclear reaction analysis study of low energy ^{13}C implanted and subsequently electron beam annealed (1 0 0) silicon ... 217 (2004) 583

Mártil, I., see Bohne, W. 217 (2004) 237
Mattoni, C.E.H., see Dzhosyuk, S.N. 217 (2004) 457
Matweev, L.V., Theoretical modeling of atom acceleration in the tracks of swift charged particles in irradiated insulators 217 (2004) 18
Mayer, M., see Barradas, N.P. 217 (2004) 479
McKinsey, D.N., see Dzhosyuk, S.N. 217 (2004) 457
McNeill, F.E., see Fleming, D.E.B. 217 (2004) 471
Min, B., see Kim, H. 217 (2004) 429
Mitra, D., see Mandal, A.C. 217 (2004) 104
Modica, R., see Codegoni, D. 217 (2004) 65
Mohan, S., see Balaji, S. 217 (2004) 423
Mohapatra, S., B. Joseph, D.P. Mahapatra and P. Chakraborty, High efficiency gettering of Au in Si(1 1 1) by MeV C implantation 217 (2004) 578
Mohr, J., see Nazmov, V. 217 (2004) 409
Moriyoshi, C., see Endo, I. 217 (2004) 666

Nakagawa, T., see Takahashi, S. 217 (2004) 435
Nakamura, N., K. Hirao and Y. Yamauchi, Surface analytical studies of ion-implanted uni-directionally aligned silicon nitride for tribological applications 217 (2004) 51
Nakamura, T., see Agosteo, S. 217 (2004) 221
Nakano, S., see Wang, Q. 217 (2004) 598
Nat, A., see Lupu, R. 217 (2004) 123
Nazmov, V., L. Shabel'nikov, F.-J. Pantenburg, J. Mohr, E. Reznikova, A. Snigirev, I. Snigireva, S. Kouznetsov and M. DiMichiel, Kinoform X-ray lens creation in polymer materials by deep X-ray lithography 217 (2004) 409
Ng, F.M.F., see Nikezic, D. 217 (2004) 637
Nie, R., see Ding, F.-R. 217 (2004) 572
Nikezic, D., F.M.F. Ng and K.N. Yu, Sensitivity of LR 115 detectors in hemispherical chambers for radon measurements 217 (2004) 637
Nordlund, K., see Peltola, J. 217 (2004) 25
Notomi, M., see Takahashi, S. 217 (2004) 435

O'Donnell, K.P., see Barradas, N.P. 217 (2004) 479
Oeyen, J., see van der Meer, K. 217 (2004) 202
Ogiso, H., see Wang, Q. 217 (2004) 598
Ohashi, N., see Sakaguchi, I. 217 (2004) 417
Ohnishi, T., see Endo, I. 217 (2004) 666
Olin, A., see Greife, U. 217 (2004) 1
Oproiu, C., see Marghitu, S. 217 (2004) 498
O'Raifeartaigh, C., R.C. Barklie and J.K.N. Lindner, EPR study of defects produced by MeV Ag ion implantation into silicon 217 (2004) 442
Orberger, B., see Gallien, J.-P. 217 (2004) 113
Otranto, S., G. Gasaneo and C.R. Garibotti, Energy and cusp-conditions study for the He isoelectronic sequence 217 (2004) 12
Ottewell, D., see Greife, U. 217 (2004) 1

Pagura, C., see Tolstogouzov, A. 217 (2004) 246
Palihawadana, P., see Ariyasinghe, W.M. 217 (2004) 389
Pantenburg, F.-J., see Nazmov, V. 217 (2004) 409
Park, D., see Sakaguchi, I. 217 (2004) 417
Park, K., see Kim, H. 217 (2004) 429
Pasava, J., see Gallien, J.-P. 217 (2004) 113
Paul, H., A note on the density effect in the stopping power for positive ions 217 (2004) 7
Pegg, D.J., see Sandström, J. 217 (2004) 513
Peltola, J., K. Nordlund and J. Keinonen, Molecular dynamics study on stopping powers of channeled He and Li ions in Si 217 (2004) 25

Pereira, E., see Barradas, N.P. 217 (2004) 479
Pereira, S., see Barradas, N.P. 217 (2004) 479
Pinti, D.L., see Gallien, J.-P. 217 (2004) 113
Ponnusamy, V., V. Ramasamy, M. Dheenathayalu and J. Hemalatha, Effect of annealing in thermostimulated luminescence (TSL) on natural blue colour calcite crystals 217 (2004) 611

Qi, D., see Zhao, Z. 217 (2004) 621
Quarta, G., M. D'Elia and L. Calcagnile, The influence of injection parameters on mass fractionation phenomena in radiocarbon analysis 217 (2004) 644
Quindós, L.S., see Fernández, P.L. 217 (2004) 167

Ramasamy, V., see Ponnusamy, V. 217 (2004) 611
Rancoita, P.G., see Codegoni, D. 217 (2004) 65
Ratajová, E., see Švorčík, V. 217 (2004) 307
Reznikova, E., see Nazmov, V. 217 (2004) 409
Ročková, K., see Švorčík, V. 217 (2004) 307
Rogers, J., see Greife, U. 217 (2004) 1
Röhrich, J., see Bohne, W. 217 (2004) 237
Rudolphi, M., see Markwitz, A. 217 (2004) 583

Saeed, U., see Biswas, A. 217 (2004) 39
Sainz, C., see Fernández, P.L. 217 (2004) 167
Sakaguchi, I., Y. Sato, D. Park, N. Ohashi, H. Haneda and S. Hishita, Recovery of the luminescence property in sulfur-implanted ZnO thin film 217 (2004) 417
San Andrés, E., see Bohne, W. 217 (2004) 237
Sandström, J., P. Andersson, K. Fritioff, D. Hanstorp, R. Thomas, D.J. Pegg and K. Wendt, Laser photodetachment mass spectrometry 217 (2004) 513
Santra, S., see Mandal, A.C. 217 (2004) 104
Saphier, D., see van der Meer, K. 217 (2004) 202
Saraydın, D., S. Ünver-Saraydın, E. Karadağ, E. Koptagel and O. Güven, In vivo biocompatibility of radiation crosslinked acrylamide copolymers 217 (2004) 281
Sarkar, D.K., see Chaudhuri, S. 217 (2004) 589
Sarkar, M., see Mandal, A.C. 217 (2004) 104
Sato, Y., see Sakaguchi, I. 217 (2004) 417
Satyam, P.V., see Balaji, S. 217 (2004) 423
Scarlat, Fl., see Marghitu, S. 217 (2004) 498
Schönbacher, H. and M. Tavlet, Absorbed doses and radiation damage during the 11 years of LEP operation 217 (2004) 77
Schöpke, A., see Bohne, W. 217 (2004) 237
Schürmann, U., see Biswas, A. 217 (2004) 39
Schut, H., see Escobar Galindo, R. 217 (2004) 262
Schwebel, C., see Coste, Ph. 217 (2004) 342
Sealy, B.J., see Boudreault, G. 217 (2004) 177
Seidman, A., see Codegoni, D. 217 (2004) 65
Selle, B., see Bohne, W. 217 (2004) 237
Shabel'nikov, L., see Nazmov, V. 217 (2004) 409
Shapiro, M.H. and T.A. Tombrello, Temporal development of sputtered atom distributions from Au(1 1 1) targets following bombardment with 100 keV/atom Au_2 ions 217 (2004) 253
Sharaf, M.A. and G.M. Hassan, ESR dosimetric properties of modern coral reef 217 (2004) 603
Sharma, S.K., see Manam, J. 217 (2004) 314
Shchagin, A.V., see Endo, I. 217 (2004) 666
Shen, D.-Y., see Ding, F.-R. 217 (2004) 572
Sheu, R.D., see Sheu, R.J. 217 (2004) 555
Sheu, R.J., J.P. Wang, R.D. Sheu and S.H. Jiang, Gas bremsstrahlung and induced photoneutrons in the NSRRC's electron storage ring: a comparison of measurements and simulations 217 (2004) 555
Shi, L., see Hu, P. 217 (2004) 551

Shi, P., see Ding, F.-R. 217 (2004) 572
Shor, A., see van der Meer, K. 217 (2004) 202
Shubin, Yu.N., see Tárkányi, F. 217 (2004) 373
Shubin, Yu., see Tárkányi, F. 217 (2004) 531
Shvartsman, V.V., see Barradas, N.P. 217 (2004) 479
Sieber, I., see Bohne, W. 217 (2004) 237
Silari, M., see Agosteo, S. 217 (2004) 221
Snigirev, A., see Nazmov, V. 217 (2004) 409
Snigireva, I., see Nazmov, V. 217 (2004) 409
Sonck, M., see Tárkányi, F. 217 (2004) 531
Sun, Q., C. Gu, X. Ma and L. Xia, Treatment homogeneity and conformal analysis of plasma based ion implanted 3D target 217 (2004) 300
Suominen, P., see Tarvainen, O. 217 (2004) 136
Suzuki, Y., see Zhu, Z. 217 (2004) 449
Švorčík, V., K. Ročková, E. Ratajová, J. Heitz, N. Huber, D. Bäuerle, L. Bačáková, B. Dvořánková and V. Hnatowicz, Cell proliferation on UV-excimer lamp modified and grafted polytetrafluoroethylene 217 (2004) 307

Takács, S., see Hermanne, A. 217 (2004) 193
Takács, S., see Tárkányi, F. 217 (2004) 373
Takács, S., see Tárkányi, F. 217 (2004) 531
Takahashi, S., M. Yoshida, M. Asano, M. Notomi and T. Nakagawa, Characterizations of heavy ion irradiated PET membranes 217 (2004) 435
Tárkányi, F., see Hermanne, A. 217 (2004) 193
Tárkányi, F., A. Hermanne, S. Takács, F. Ditrói, A.I. Dityuk and Yu.N. Shubin, Excitation functions for production of radioisotopes of niobium, zirconium and yttrium by irradiation of zirconium with deuterons 217 (2004) 373
Tárkányi, F., S. Takács, F. Ditrói, A. Hermanne, M. Sonck and Yu. Shubin, Excitation functions of deuteron induced nuclear reactions on natural zinc up to 50 MeV 217 (2004) 531
Tarvainen, O., P. Suominen and H. Koivisto, Effect of the gas mixing technique on the production efficiency of ion beams extracted from an electron cyclotron resonance ion source 217 (2004) 136
Tavlet, M., see Schönbacher, H. 217 (2004) 77
Teichert, S., see Chaudhuri, S. 217 (2004) 589
Tello Saenz, C.A., see Guedes, S. 217 (2004) 627
Tesfamichael, T., G. Will, I. Kelly and J. Bell, Analysis of nitrogen implanted tin oxide films used in dye-sensitised solar cells 217 (2004) 97
Thomas, R., see Sandström, J. 217 (2004) 513
Thompson, A.K., see Dzhosyuk, S.N. 217 (2004) 457
Tohno, S., see Ma, C.-J. 217 (2004) 657
Tolstogouzov, A., S. Daolio and C. Pagura, MARISS study on ion yields of Ne^+ scattered from III–V compound semiconductors 217 (2004) 246
Tombrello, T.A., see Shapiro, M.H. 217 (2004) 253
Townsend, P.D., see Yang, B. 217 (2004) 60
Trompetter, W.J., see Markwitz, A. 217 (2004) 583

Ünver-Saraydın, S., see Saraydın, D. 217 (2004) 281

van der Meer, K., M.B. Goldberg, E.H. Lehmann, H. Ait Abderrahim, D. Bar, D. Berkovits, M. Daum, S. Dekelver, Y. Foucher, J. Gerber, F. Van Gestel, W. Hajdas, H.-P. Linder, E. Malambu, I. Mardor, J. Oeyen, D. Saphier, A. Shor, M. Willekens and Y. Yariv, Spallation yields of neutrons produced in thick lead/bismuth targets by protons at incident energies of 420 and 590 MeV 217 (2004) 202
Van Gestel, F., see van der Meer, K. 217 (2004) 202
van Veen, A., see Escobar Galindo, R. 217 (2004) 262
van Veen, A., see Evans, J.H. 217 (2004) 276
von Bohlen, A., H. Krzyżanowska and R. Klockenkämper, A broad beam ion source used for planar sputter-etching of shallow layers from flat samples and determination of their mass density 217 (2004) 158

Wang, J.P., see Sheu, R.J. 217 (2004) 555
Wang, Q., H. Ishikawa, H. Ogiso, S. Nakano and J. Akedo, Effects of substrate temperature during implantation on the mechanical properties of ion-implanted silicon 217 (2004) 598
Wang, Y., see Ding, F.-R. 217 (2004) 572
Wartski, L., see Coste, Ph. 217 (2004) 342
Watson, I.M., see Barradas, N.P. 217 (2004) 479
Weedon, A.G.P., see Fleming, D.E.B. 217 (2004) 471
Wendt, K., see Sandström, J. 217 (2004) 513
Wijeratne, T., see Ariyasinghe, W.M. 217 (2004) 389
Will, G., see Tesfamichael, T. 217 (2004) 97
Willekens, M., see van der Meer, K. 217 (2004) 202
Wrede, C., see Greife, U. 217 (2004) 1

Xia, L., see Sun, Q. 217 (2004) 300
Xu, J., see Bai, X.D. 217 (2004) 293
Xu, J.L. and J.Y. Feng, Molecular-dynamics simulation of $Si_{1-x}Ge_x$ epitaxial growth on Si(100) 217 (2004) 33

Yamauchi, Y., see Nakamura, N. 217 (2004) 51
Yang, B., P.D. Townsend and R. Fromknecht, Radioluminescence detection of bulk effects in $SrTiO_3$ induced by surface ion implantation 217 (2004) 60
Yang, D., see Hu, Z. 217 (2004) 321
Yang, L., see Dzhosyuk, S.N. 217 (2004) 457
Yao, T., see Kim, H. 217 (2004) 429
Yariv, Y., see van der Meer, K. 217 (2004) 202
Yonezawa, N., see Zhu, Z. 217 (2004) 449
Yoshida, M., see Takahashi, S. 217 (2004) 435
Yoshida, M., see Zhu, Z. 217 (2004) 449
Yu, K.N., see Nikezic, D. 217 (2004) 637

Zajacova, Z., see Agosteo, S. 217 (2004) 221
Zaporojtchenko, V., see Biswas, A. 217 (2004) 39
Zays, Z., see Dias da Cunha, K. 217 (2004) 649
Zengin, R. and M. Ceylan, Effects of γ irradiation on the characteristics of the Cu–13wt.%Al–4wt.%Ni shape memory alloy 217 (2004) 327
Zhang, J., see Hu, P. 217 (2004) 551
Zhao, Z., D. Qi and Z. Guo, Etching characteristics for tracks of carbon cluster ions in polycarbonate 217 (2004) 621
Zhou, Q.G., see Bai, X.D. 217 (2004) 293
Zhou, Z., see Hu, P. 217 (2004) 551
Zhu, Z., Y. Maekawa, H. Koshikawa, Y. Suzuki, N. Yonezawa and M. Yoshida, Role of UV light illumination and DMF soaking in production of PET ion track membranes 217 (2004) 449

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Subject index

Basic Data for Materials Modification and Analysis

Energy loss around the stopping power maximum of Ne, Mg and Na ions in hydrogen gas, U. Greife, S. Bishop, L. Buchmann, M.L. Chatterjee, A.A. Chen, J.M. D'Auria, S. Engel, D. Gigliotti, D. Hunter, D.A. Hutcheon, A. Hussein, C.C. Jewett, A.M. Laird, M. Lamey, W. Liu, A. Olin, D. Ottewell, J. Rogers and C. Wrede. . 217 (2004) 1
A note on the density effect in the stopping power for positive ions, H. Paul 217 (2004) 7
Energy and cusp-conditions study for the He isoelectronic sequence, S. Otranto, G. Gasaneo and C.R. Garibotti 217 (2004) 12
Experimental cross sections for charged particle production of the therapeutic radionuclide ^{111}Ag and its PET imaging analogue ^{103m,g}Ag, A. Hermanne, S. Takács, F. Tárkányi and R. Bolbos 217 (2004) 193
Spallation yields of neutrons produced in thick lead/bismuth targets by protons at incident energies of 420 and 590 MeV, K. van der Meer, M.B. Goldberg, E.H. Lehmann, H. Aït Abderrahim, D. Bar, D. Berkovits, M. Daum, S. Dekelver, Y. Foucher, J. Gerber, F. Van Gestel, W. Hajdas, H.-P. Linder, E. Malambu, I. Mardor, J. Oeyen, D. Saphier, A. Shor, M. Willekens and Y. Yariv 217 (2004) 202
Attenuation curves in concrete of neutrons from 100 to 400 MeV per nucleon He, C, Ne, Ar, Fe and Xe ions on various targets, S. Agosteo, T. Nakamura, M. Silari and Z. Zajacova 217 (2004) 221
Excitation functions for production of radioisotopes of niobium, zirconium and yttrium by irradiation of zirconium with deuterons, F. Tárkányi, A. Hermanne, S. Takács, F. Ditrói, A.I. Dityuk and Yu.N. Shubin 217 (2004) 373
Total electron scattering cross sections of CH_4 and NH_3 molecules in the energy range 400–4000 eV, W.M. Ariyasinghe, T. Wijeratne and P. Palihawadana 217 (2004) 389
Excitation functions of deuteron induced nuclear reactions on natural zinc up to 50 MeV, F. Tárkányi, S. Takács, F. Ditrói, A. Hermanne, M. Sonck and Yu. Shubin 217 (2004) 531
Proton elastic scattering cross sections of titanium from 1.0 to 3.0 MeV at the laboratory angle of 151°, P. Hu, J. Zhang, Q. Jin, L. Shi and Z. Zhou. 217 (2004) 551
Gas bremsstrahlung and induced photoneutrons in the NSRRC's electron storage ring: a comparison of measurements and simulations, R.J. Sheu, J.P. Wang, R.D. Sheu and S.H. Jiang. 217 (2004) 555

Atomic Collisions in Solids

Theoretical modeling of atom acceleration in the tracks of swift charged particles in irradiated insulators, L.V. Matweev 217 (2004) 18
Molecular dynamics study on stopping powers of channeled He and Li ions in Si, J. Peltola, K. Nordlund and J. Keinonen. 217 (2004) 25
Compositional analysis of thin SiO_xN_y:H films by heavy-ion ERDA, standard RBS, EDX and AES: a comparison, W. Bohne, J. Röhrich, A. Schöpke, B. Selle, I. Sieber, W. Fuhs, Á. del Prado, E. San Andrés, I. Mártil and G. González-Díaz 217 (2004) 237
MARISS study on ion yields of Ne^+ scattered from III–V compound semiconductors, A. Tolstogouzov, S. Daolio and C. Pagura 217 (2004) 246
Temporal development of sputtered atom distributions from Au(111) targets following bombardment with 100 keV/atom Au_2 ions, M.H. Shapiro and T.A. Tombrello. 217 (2004) 253
Protrusion formation and surface porosity development on thermally annealed helium implanted copper, R. Escobar Galindo, A. van Veen, J.H. Evans, H. Schut and J.Th.M. de Hosson 217 (2004) 262
Dependence of amorphization energies in SiC on electronic stopping, E. Friedland 217 (2004) 396
Scattering and self-absorption corrections in the measurement of α-particle emitters in 2π geometry, M. Jurado Vargas and A. Fernández Timón 217 (2004) 564
Secondary ion emissions from carbon nanotubes induced by MeV Si and Si_2 clusters, F.-R. Ding, P. Shi, W.-H. He, Y. Wang, R. Nie, D.-Y. Shen and H.-J. Ma 217 (2004) 572

doi:10.1016/S0168-583X(04)00446-X

On the origin of mysterious X-ray spectral peaks observed at the REFER electron ring, I. Endo, D. Iseki, T. Ohnishi, C. Moriyoshi and A.V. Shchagin 217 (2004) 666

Ion and Laser Beam Modification of Materials

Molecular-dynamics simulation of $Si_{1-x}Ge_x$ epitaxial growth on Si(100), J.L. Xu and J.Y. Feng 217 (2004) 33
Nanoparticle architecture in carbonaceous matrix upon swift heavy ion irradiation of polymer–metal nanocomposites, A. Biswas, D.K. Avasthi, D. Fink, J. Kanzow, U. Schürmann, S.J. Ding, O.C. Aktas, U. Saeed, V. Zaporojtchenko, F. Faupel, R. Gupta and N. Kumar 217 (2004) 39
Surface analytical studies of ion-implanted uni-directionally aligned silicon nitride for tribological applications, N. Nakamura, K. Hirao and Y. Yamauchi 217 (2004) 51
A description of bubble growth and gas release during thermal annealing of helium implanted copper, J.H. Evans, R. Escobar Galindo and A. van Veen 217 (2004) 276
In vivo biocompatibility of radiation crosslinked acrylamide copolymers, D. Saraydın, S. Ünver-Saraydın, E. Karadağ, E. Koptagel and O. Güven 217 (2004) 281
Corrosion resistance and microstructure of zircaloy-4 subjected to ion irradiation, X.D. Bai, X.W. Chen, J. Xu, Q.G. Zhou and B.S. Chen 217 (2004) 293
Treatment homogeneity and conformal analysis of plasma based ion implanted 3D target, Q. Sun, C. Gu, X. Ma and L. Xia 217 (2004) 300
Study of the chemical and morphological evolution of the GaAs surface after high fluence focused ion beam exposure, A. Lugstein, B. Basnar and E. Bertagnolli 217 (2004) 402
Kinoform X-ray lens creation in polymer materials by deep X-ray lithography, V. Nazmov, L. Shabel'nikov, F.-J. Pantenburg, J. Mohr, E. Reznikova, A. Snigirev, I. Snigireva, S. Kouznetsov and M. DiMichiel 217 (2004) 409
Recovery of the luminescence property in sulfur-implanted ZnO thin film, I. Sakaguchi, Y. Sato, D. Park, N. Ohashi, H. Haneda and S. Hishita 217 (2004) 417
Influence of secondary ion bombardment on the composition, structure and surface properties of platinum thin films, S. Balaji, P.V. Satyam, V. Lakshminarayanan and S. Mohan 217 (2004) 423
Transmuted isotopes doped in neutron-irradiated ZnO thin films, H. Kim, K. Park, B. Min, J.S. Lee, K. Cho, S. Kim, H.S. Han, S.K. Hong and T. Yao 217 (2004) 429
Characterizations of heavy ion irradiated PET membranes, S. Takahashi, M. Yoshida, M. Asano, M. Notomi and T. Nakagawa 217 (2004) 435
High efficiency gettering of Au in Si(111) by MeV C implantation, S. Mohapatra, B. Joseph, D.P. Mahapatra and P. Chakraborty 217 (2004) 578
SiC nanoboulders on silicon – a nuclear reaction analysis study of low energy ^{13}C implanted and subsequently electron beam annealed (1 0 0) silicon, A. Markwitz, V.J. Kennedy, S. Johnson, W.J. Trompetter, M. Rudolphi and H. Baumann 217 (2004) 583
Formation of transition metal silicides by high energy ion beam mixing in Mn/Si and Ni/Si single and multilayer samples, S. Chaudhuri, S. Biswas, A. Gupta, D.K. Avasthi, D. Bhattacharyya, S. Teichert and D.K. Sarkar 217 (2004) 589
Effects of substrate temperature during implantation on the mechanical properties of ion-implanted silicon, Q. Wang, H. Ishikawa, H. Ogiso, S. Nakano and J. Akedo 217 (2004) 598

Effects of Radiation

Radioluminescence detection of bulk effects in $SrTiO_3$ induced by surface ion implantation, B. Yang, P.D. Townsend and R. Fromknecht 217 (2004) 60
Investigation of irradiated monolithic transistors for space applications, D. Codegoni, A. Colder, N. Croitoru, P. D'Angelo, M. DeMarchi, G. Fallica, A. Favalli, S. Leonardi, M. Levalois, P. Marie, R. Modica, P.G. Rancoita and A. Seidman 217 (2004) 65
Absorbed doses and radiation damage during the 11 years of LEP operation, H. Schönbacher and M. Tavlet . 217 (2004) 77
Cell proliferation on UV-excimer lamp modified and grafted polytetrafluoroethylene, V. Švorčík, K. Röčková, E. Ratajová, J. Heitz, N. Huber, D. Bäuerle, L. Bačáková, B. Dvořánková and V. Hnatowicz 217 (2004) 307
Thermally stimulated luminescence studies of undoped and doped $K_2B_4O_7$ compounds, J. Manam and S.K. Sharma 217 (2004) 314
Effect of <200 keV proton radiation on electric properties of silicon solar cells at 77 K, Z. Hu, S. He and D. Yang 217 (2004) 321
Effects of γ irradiation on the characteristics of the Cu–13wt.%Al–4wt.%Ni shape memory alloy, R. Zengin and M. Ceylan 217 (2004) 327

EPR study of defects produced by MeV Ag ion implantation into silicon, C. O'Raifeartaigh, R.C. Barklie and J.K.N. Lindner . . . 217 (2004) 442
Role of UV light illumination and DMF soaking in production of PET ion track membranes, Z. Zhu, Y. Maekawa, H. Koshikawa, Y. Suzuki, N. Yonezawa and M. Yoshida . . . 217 (2004) 449
Neutron-induced luminescence and activation in neutron shielding and scintillation detection materials at cryogenic temperatures, S.N. Dzhosyuk, C.E.H. Mattoni, D.N. McKinsey, A.K. Thompson, L. Yang, J.M. Doyle and P.R. Huffman . . . 217 (2004) 457
ESR dosimetric properties of modern coral reef, M.A. Sharaf and G.M. Hassan . . . 217 (2004) 603
Effect of annealing in thermostimulated luminescence (TSL) on natural blue colour calcite crystals, V. Ponnusamy, V. Ramasamy, M. Dheenathayalu and J. Hemalatha . . . 217 (2004) 611
Etching characteristics for tracks of carbon cluster ions in polycarbonate, Z. Zhao, D. Qi and Z. Guo . . . 217 (2004) 621
Kinetic model for the relationship between confined fission-track length shortening and fission-track age reduction in minerals, S. Guedes, J.C. Hadler Neto, P. José Iunes and C.A. Tello Saenz . . . 217 (2004) 627
Sensitivity of LR 115 detectors in hemispherical chambers for radon measurements, D. Nikezic, F.M.F. Ng and K.N. Yu . . . 217 (2004) 637

Analysis of Materials

Analysis of nitrogen implanted tin oxide films used in dye-sensitised solar cells, T. Tesfamichael, G. Will, I. Kelly and J. Bell . . . 217 (2004) 97
Bremsstrahlung excited standardless EDXRF analysis, A.C. Mandal, S. Santra, D. Mitra, M. Sarkar and D. Bhattacharya . . . 217 (2004) 104
Nitrogen in biogenic and abiogenic minerals from Paleozoic black shales: an NRA study, J.-P. Gallien, B. Orberger, L. Daudin, D.L. Pinti and J. Pasava . . . 217 (2004) 113
Determination of gold in Romanian auriferous alluvial sands and rocks by 14 MeV neutron activation analysis, R. Lupu, A. Nat and A. Ene . . . 217 (2004) 123
Final energy distributions in deep inelastic neutron scattering experiments, J.J. Blostein, J. Dawidowski and J.R. Granada . . . 217 (2004) 333
Effects of measurement distance and source activity on the precision of X-ray fluorescence measurements of lead in a bone phantom, D.E.B. Fleming, D.R. Chettle, F.E. McNeill and A.G.P. Weedon . . . 217 (2004) 471
Roughness in GaN/InGaN films and multilayers determined with Rutherford backscattering, N.P. Barradas, E. Alves, S. Pereira, V.V. Shvartsman, A.L. Kholkin, E. Pereira K.P. O'Donnell, C. Liu, C.J. Deatcher, I.M. Watson and M. Mayer . . . 217 (2004) 479
The influence of injection parameters on mass fractionation phenomena in radiocarbon analysis, G. Quarta, M. D'Elia and L. Calcagnile . . . 217 (2004) 644
Exposure to mineral sands dust particles, K. Dias da Cunha, C.V. Barros Leite and Z. Zays . . . 217 (2004) 649
Determination of the chemical properties of residues retained in individual cloud droplets by XRF microprobe at SPring-8, C.-J. Ma, S. Tohno, M. Kasahara and S. Hayakawa . . . 217 (2004) 657

Ion Sources, Beam Optics and Accelerator Systems

Effect of the gas mixing technique on the production efficiency of ion beams extracted from an electron cyclotron resonance ion source, O. Tarvainen, P. Suominen and H. Koivisto . . . 217 (2004) 136
Simplified modelling of an ion linac used for ion implantation, J. Gordon . . . 217 (2004) 143
A broad beam ion source used for planar sputter-etching of shallow layers from flat samples and determination of their mass density, A. von Bohlen, H. Krzyżanowska and R. Klockenkämper . . . 217 (2004) 158
A simple microwave component for the vacuum window protection in an ECR ion source for ion beam processing, Ph. Coste, L. Wartski, J. Aubert and C. Schwebel . . . 217 (2004) 342
The effect of electrode geometry on the stability of a liquid metal ion emitter, G.L.R. Mair, Ch. Akhmadaliev, L. Bischoff, Th. Ganetsos, C.J. Aidinis and E.A. Anagnostakis . . . 217 (2004) 347
Diagnosis and dynamics in a simple low energy medium current electron beam channel, S. Marghitu, O. Marghitu, C. Oproiu, G. Marin and Fl. Scarlat . . . 217 (2004) 498
The PTB single ion microbeam for irradiation of living cells, K.-D. Greif, H.J. Brede, D. Frankenberg and U. Giesen . . . 217 (2004) 505
Laser photodetachment mass spectrometry, J. Sandström, P. Andersson, K. Fritioff, D. Hanstorp, R. Thomas, D.J. Pegg and K. Wendt . . . 217 (2004) 513

Experimental Methods and Equipment

A theoretical approach to the measurement of radon diffusion and adsorption coefficients in radonproof membranes, P.L. Fernández, L.S. Quindós, C. Sainz and J. Gómez 217 (2004) 167
Accurate calibration of the retained fluence from a versatile single wafer implanter using RBS, G. Boudreault, G. Claudio, C. Jeynes, R. Low and B.J. Sealy 217 (2004) 177
Mathematical model of the electronuclear set-up on the beam of JINR synchrotron, V.S. Barashenkov, H. Kumawat, V.A. Lobanova and V. Kumar 217 (2004) 352
A digital detector performance evaluation using Monte Carlo technique, E.P.Q. Alcón 217 (2004) 361

Letters to the Editor

On the concept of an actual Coulomb barrier, A.F. Gurbich 217 (2004) 183
A method for improving the efficiency of proton microprobe profiling of strontium in otoliths using a vacuum compatible NaI detector, B. Barry and A. Markwitz 217 (2004) 521
On the origin of mysterious X-ray spectral peaks observed at the REFER electron ring, I. Endo, D. Iseki, T. Ohnishi, C. Moriyoshi and A.V. Shchagin 217 (2004) 666